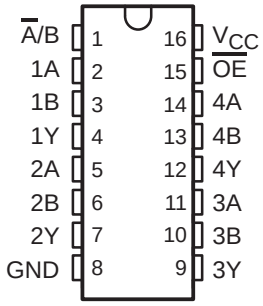
- ***EPIC***™ **(Enhanced-Performance Implanted CMOS) Submicron Process**
- **Typical $V_{OLP}$ (Output Ground Bounce) < 0.8 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Typical $V_{OHV}$ (Output $V_{OH}$ Undershoot) > 2 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Inputs Accept Voltages to 5.5 V**
- **Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages**

**D, DB, OR PW PACKAGE**
**(TOP VIEW)**




## description

This quadruple 2-line to 1-line data selector/multiplexer is designed for 1.65-V to 3.6-V $V_{CC}$ operation.

The SN74LVC258A is designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable ($\overline{OE}$) input is at a high logic level.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to $V_{CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74LVC258A is characterized for operation from –40°C to 85°C.

**FUNCTION TABLE**

| INPUTS | | | | OUTPUT |
|---|---|---|---|---|
| $\overline{OE}$ | $\overline{A}$/B | A | B | Y |
| H | X | X | X | Z |
| L | L | L | X | H |
| L | L | H | X | L |
| L | H | X | L | H |
| L | H | X | H | L |

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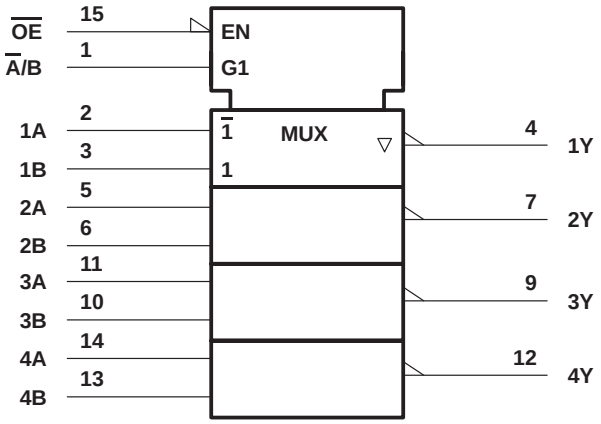
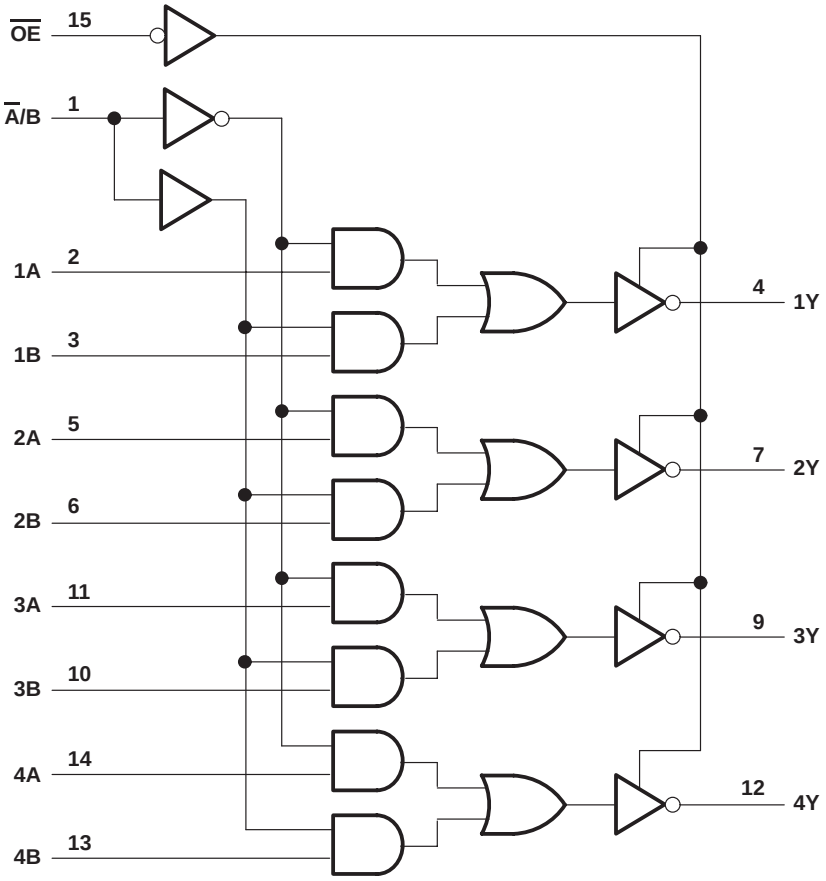
## logic symbol†




† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$ . . . . . –0.5 V to 6.5 V
Input voltage range, $V_I$ (see Note 1) . . . . . –0.5 V to 6.5 V
Output voltage range, $V_O$ (see Notes 1 and 2) . . . . . –0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, $I_{IK}$ ($V_I$ < 0) . . . . . –50 mA
Output clamp current, $I_{OK}$ ($V_O$ < 0) . . . . . –50 mA
Continuous output current, $I_O$ . . . . . ±50 mA
Continuous current through $V_{CC}$ or GND . . . . . ±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): D package . . . . . 113°C/W
DB package . . . . . 131°C/W
PW package . . . . . 149°C/W
Storage temperature range, $T_{stg}$ . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The value of $V_{CC}$ is provided in the recommended operating conditions table.
3. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions (see Note 4)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage | Operating | 1.65 | 3.6 | V |
| | | Data retention only | 1.5 | | |
| $V_{IH}$ | High-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | 0.65 × $V_{CC}$ | | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 1.7 | | |
| | | $V_{CC}$ = 2.7 V to 3.6 V | 2 | | |
| $V_{IL}$ | Low-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | | 0.35 × $V_{CC}$ | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | | 0.7 | |
| | | $V_{CC}$ = 2.7 V to 3.6 V | | 0.8 | |
| $V_I$ | Input voltage | | 0 | 5.5 | V |
| $V_O$ | Output voltage | | 0 | $V_{CC}$ | V |
| $I_{OH}$ | High-level output current | $V_{CC}$ = 1.65 V | | –4 | mA |
| | | $V_{CC}$ = 2.3 V | | –8 | |
| | | $V_{CC}$ = 2.7 V | | –12 | |
| | | $V_{CC}$ = 3 V | | –24 | |
| $I_{OL}$ | Low-level output current | $V_{CC}$ = 1.65 V | | 4 | mA |
| | | $V_{CC}$ = 2.3 V | | 8 | |
| | | $V_{CC}$ = 2.7 V | | 12 | |
| | | $V_{CC}$ = 3 V | | 24 | |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | | 0 | 10 | ns/V |
| $T_A$ | Operating free-air temperature | | –40 | 85 | °C |

NOTE 4: All unused inputs of the device must be held at $V_{CC}$ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | $V_{CC}$ | MIN | TYP† | MAX | UNIT |
|---|---|---|---|---|---|---|
| $V_{OH}$ | $I_{OH}$ = –100 μA | 1.65 V to 3.6 V | $V_{CC}$–0.2 | | | V |
| | $I_{OH}$ = –4 mA | 1.65 V | 1.2 | | | |
| | $I_{OH}$ = –8 mA | 2.3 V | 1.7 | | | |
| | $I_{OH}$ = –12 mA | 2.7 V | 2.2 | | | |
| | | 3 V | 2.4 | | | |
| | $I_{OH}$ = –24 mA | 3 V | 2.2 | | | |
| $V_{OL}$ | $I_{OL}$ = 100 μA | 1.65 V to 3.6 V | | | 0.2 | V |
| | $I_{OL}$ = 4 mA | 1.65 V | | | 0.45 | |
| | $I_{OL}$ = 8 mA | 2.3 V | | | 0.7 | |
| | $I_{OL}$ = 12 mA | 2.7 V | | | 0.4 | |
| | $I_{OL}$ = 24 mA | 3 V | | | 0.55 | |
| $I_I$ | $V_I$ = 5.5 V or GND | 3.6 V | | | ±5 | μA |
| $I_{OZ}$ | $V_O = V_{CC}$ or GND | 3.6 V | | | ±10 | μA |
| $I_{CC}$ | $V_I = V_{CC}$ or GND, $I_O$ = 0 | 3.6 V | | | 10 | μA |
| $\Delta I_{CC}$ | One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND | 2.7 V to 3.6 V | | | 500 | μA |
| $C_i$ | $V_I = V_{CC}$ or GND | 3.3 V | | | | pF |
| $C_o$ | $V_O = V_{CC}$ or GND | 3.3 V | | | | pF |

† All typical values are at $V_{CC}$ = 3.3 V, $T_A$ = 25°C.

### switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

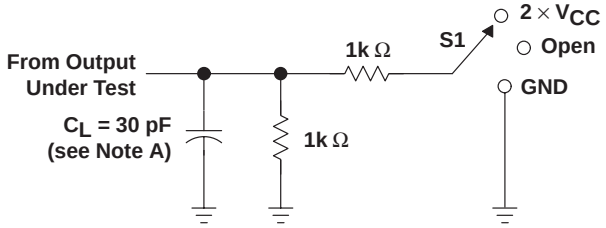
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ = 1.8 V ± 0.15 V | | $V_{CC}$ = 2.5 V ± 0.2 V | | $V_{CC}$ = 2.7 V | | $V_{CC}$ = 3.3 V ± 0.3 V | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| $t_{pd}$ | A or B | Y | | | | | | | | | ns |
| | $\overline{A}$/B | | | | | | | | | | |
| $t_{en}$ | $\overline{OE}$ | Y | | | | | | | | | ns |
| $t_{dis}$ | $\overline{OE}$ | Y | | | | | | | | | ns |
| $t_{sk(o)}$‡ | | | | | | | | | | | ns |

‡ Skew between any two outputs of the same package switching in the same direction

### operating characteristics, $T_A$ = 25°C

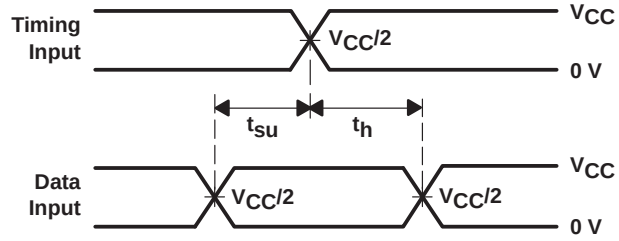
| PARAMETER | | TEST CONDITIONS | $V_{CC}$ = 1.8 V ± 0.15 V | $V_{CC}$ = 2.5 V ± 0.2 V | $V_{CC}$ = 3.3 V ± 0.3 V | UNIT |
|---|---|---|---|---|---|---|
| | | | TYP | TYP | TYP | |
| $C_{pd}$ | Power dissipation capacitance | f = 10 MHz | | | | pF |

## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 1.8 V ± 0.15 V

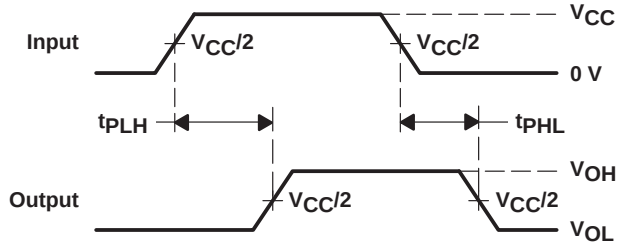



| TEST | S1 |
|---|---|
| $t_{pd}$ | Open |
| $t_{PLZ}/t_{PZL}$ | 2 × $V_{CC}$ |
| $t_{PHZ}/t_{PZH}$ | Open |

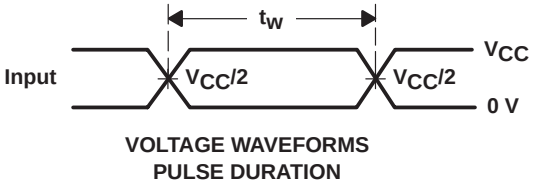
LOAD CIRCUIT



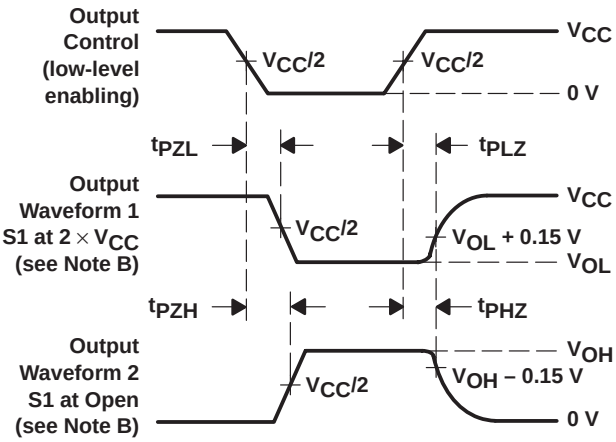

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES




VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2 ns, $t_f$ ≤ 2 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

**Figure 1. Load Circuit and Voltage Waveforms**

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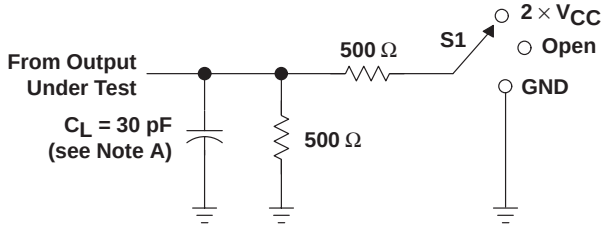
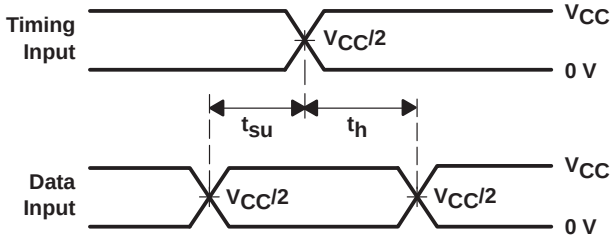
## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 2.5 V ± 0.2 V

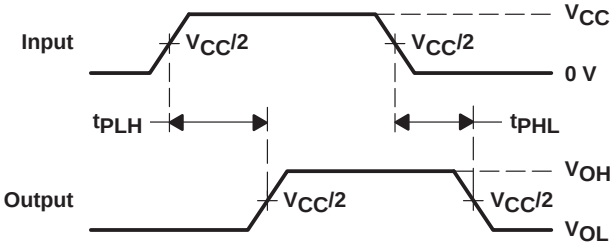



| TEST | S1 |
|---|---|
| $t_{pd}$<br>$t_{PLZ}/t_{PZL}$<br>$t_{PHZ}/t_{PZH}$ | Open<br>2 × $V_{CC}$<br>GND |

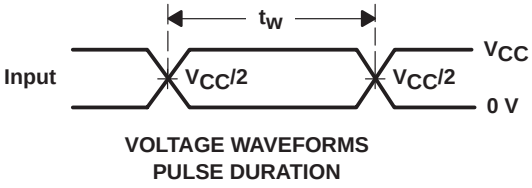
LOAD CIRCUIT



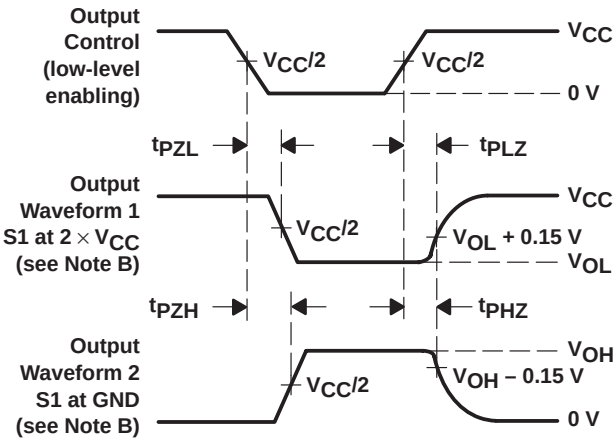

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES




VOLTAGE WAVEFORMS
PULSE DURATION

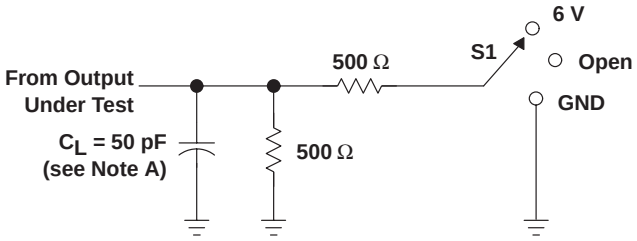



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2 ns, $t_f$ ≤ 2 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

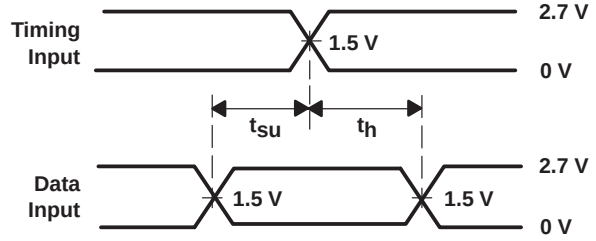
**Figure 2. Load Circuit and Voltage Waveforms**

## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 2.7 V AND 3.3 V ± 0.3 V

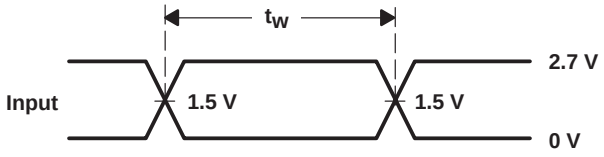



| TEST | S1 |
|---|---|
| $t_{pd}$ | Open |
| $t_{PLZ}/t_{PZL}$ | 6 V |
| $t_{PHZ}/t_{PZH}$ | GND |

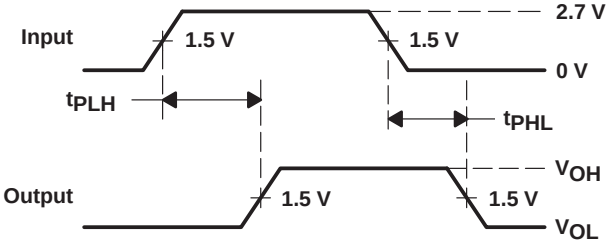
LOAD CIRCUIT



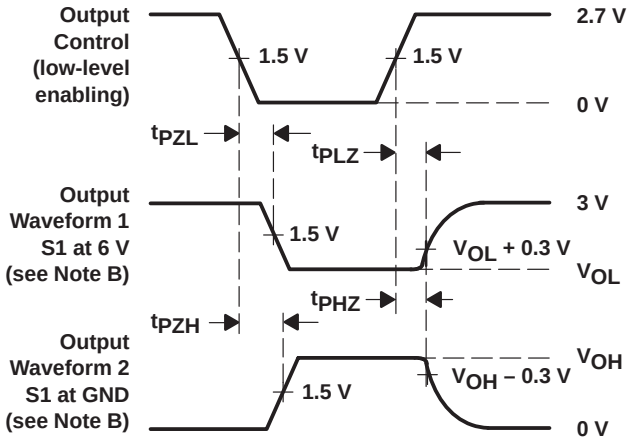

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2.5 ns, $t_f$ ≤ 2.5 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

**Figure 3. Load Circuit and Voltage Waveforms**

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